ABSTRACT

The present invention relates to:

a polymer for an anode buffer layer in an organic light emitting device comprising a self-doping conductive polymer having a pH value of 3 to 7 in a 1% by mass aqueous solution, the polymer containing monomer unit(s) represented by the following formula (1) and/or (2):

$$(SO_3^-M^+)_k$$

10

15

20

5

$$(SO_3)_k$$

wherein M^+ represents a hydrogen ion, an alkali metal ion, or a quaternary ammonium ion, k represents 1 or 2, +k represents a positive charge number, and a hydrogen atom in the aromatic ring may be replaced by a substituent,

an anode buffer layer coating solution comprising the polymer, and an organic light emitting device comprising an anode buffer layer using the polymer. The polymer of the present invention can overcome the problem of deterioration of light emitting layer due to extrinsic dopant.